

P-Channel Power MOSFET

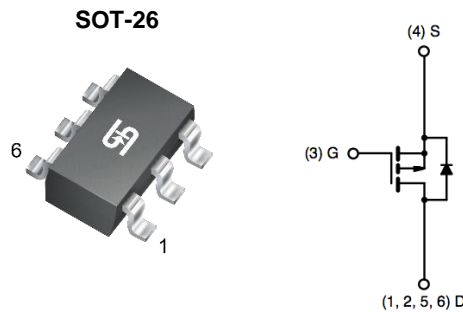
FEATURES

- Advance trench process technology
- RoHS compliant
- Halogen-free

APPLICATIONS

- Power management
- Load switch
- Battery protection

KEY PERFORMANCE PARAMETERS		
PARAMETER	VALUE	UNIT
V_{DS}	-20	V
$R_{DS(on)}$ (max)	$V_{GS} = -4.5V$	60
	$V_{GS} = -2.5V$	100
Q_g	9.5	nC



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 10	V
Continuous Drain Current	I_D	-4.3	A
Pulsed Drain Current (Note 1)	I_{DM}	-17.2	A
Total Power Dissipation	P_D	1.56	W
		1	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	- 55 to +150	$^\circ C$

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Ambient Thermal Resistance (Note 2)	$R_{\theta JA}$	80	$^\circ C/W$

Notes:

1. Pulse Width $\leq 100\mu s$.
2. Device on a PCB FR4 with 1 in² (single layer, 2 oz thickness) copper area for drain connection.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 3)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV_{DSS}	-20	--	--	V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\mu A$	$V_{GS(TH)}$	-0.5	-0.6	-1.4	V
Gate Body Leakage	$V_{GS} = \pm 10V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -20V, V_{GS} = 0V$	I_{DSS}	--	--	-1	μA
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_D = -4.3A$	$R_{DS(on)}$	--	29	60	m Ω
	$V_{GS} = -2.5V, I_D = -3.3A$		--	35	100	
Forward Transconductance	$V_{DS} = -10V, I_D = -1.1A$	g_{fs}	--	9.6	--	S
Dynamic (Note 4)						
Total Gate Charge	$V_{DS} = -10V, I_D = -4.3A,$ $V_{GS} = -4.5V$	Q_g	--	9.5	--	nC
Gate-Source Charge		Q_{gs}	--	1.2	--	
Gate-Drain Charge		Q_{gd}	--	2.3	--	
Input Capacitance	$V_{DS} = -10V, V_{GS} = 0V,$ $f = 1.0\text{MHz}$	C_{iss}	--	793	--	pF
Output Capacitance		C_{oss}	--	491	--	
Reverse Transfer Capacitance		C_{rss}	--	102	--	
Switching (Note 5)						
Turn-On Delay Time	$V_{DD} = -10V, R_G = 6\Omega,$ $I_D = -4.3A, V_{GS} = -4.5V$	$t_{d(on)}$	--	7.8	--	ns
Turn-On Rise Time		t_r	--	17	--	
Turn-Off Delay Time		$t_{d(off)}$	--	81	--	
Turn-Off Fall Time		t_f	--	45	--	
Source-Drain Diode						
Forward Voltage (Note 3)	$I_S = -4.3A, V_{GS} = 0V$	V_{SD}	--	0.7	1.2	V

Notes:

3. Pulse test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
4. Defined by design. Not subject to production test.
5. Switching time is essentially independent of operating temperature.

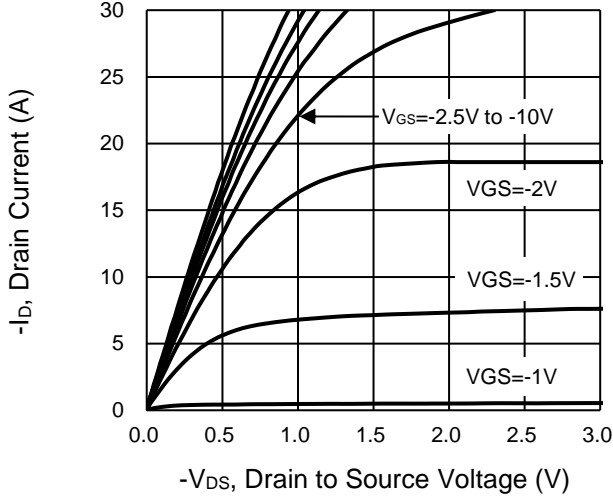
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSM3443CX6 RFG	SOT-26	3kpcs / 7" Reel

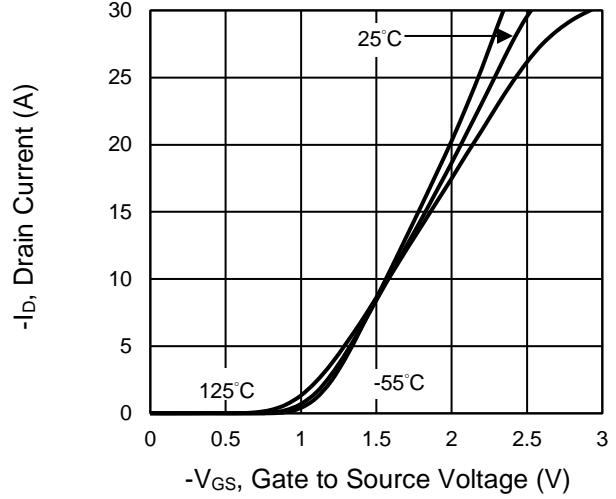
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

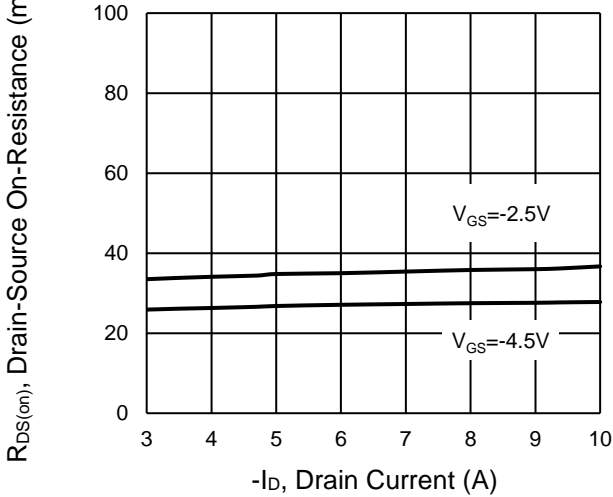
Output Characteristics



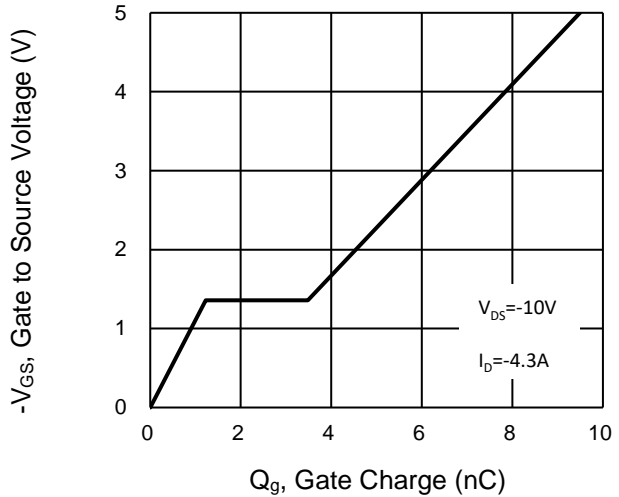
Transfer Characteristics



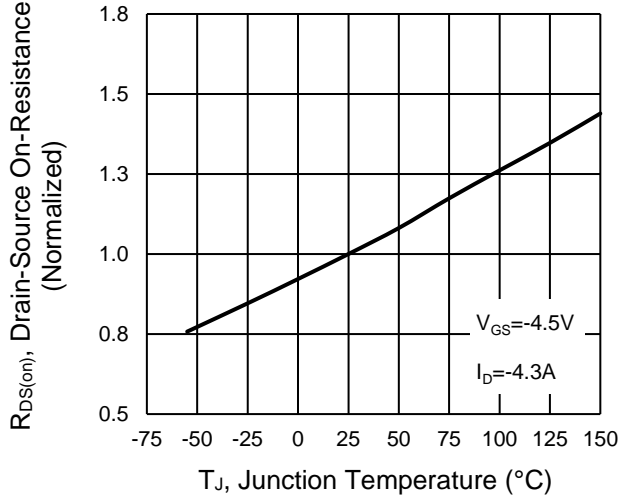
On-Resistance vs. Drain Current



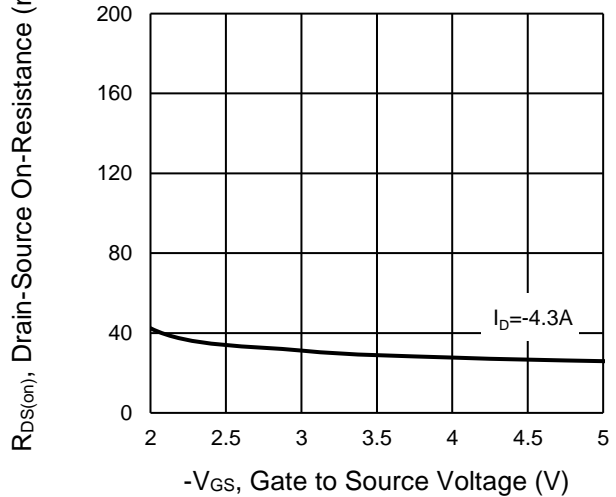
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature



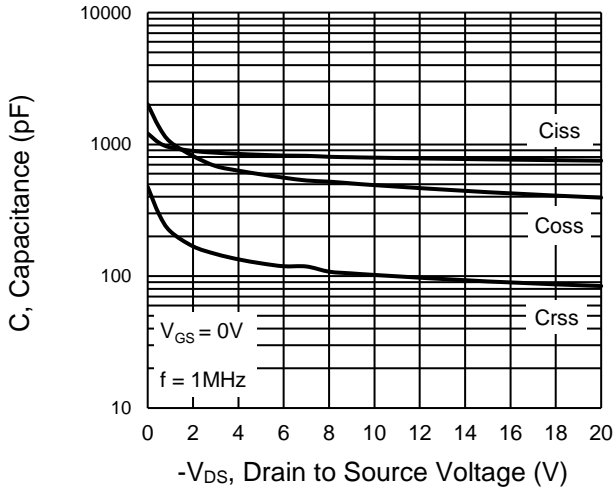
On-Resistance vs. Gate-Source Voltage



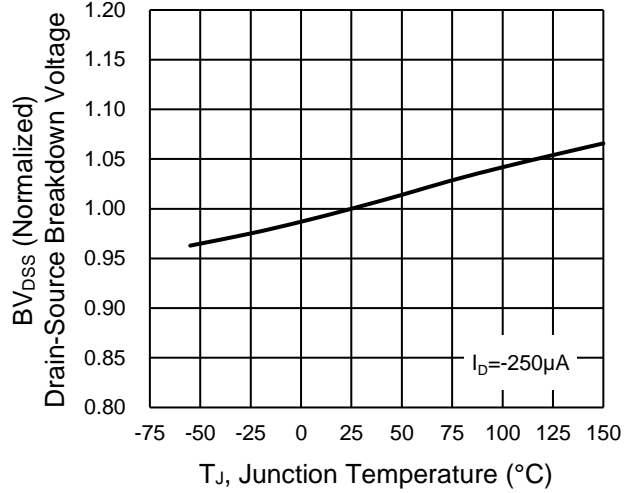
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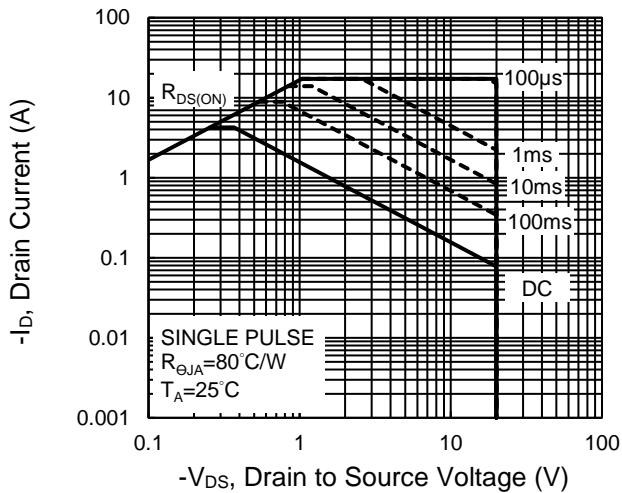
Capacitance vs. Drain-Source Voltage



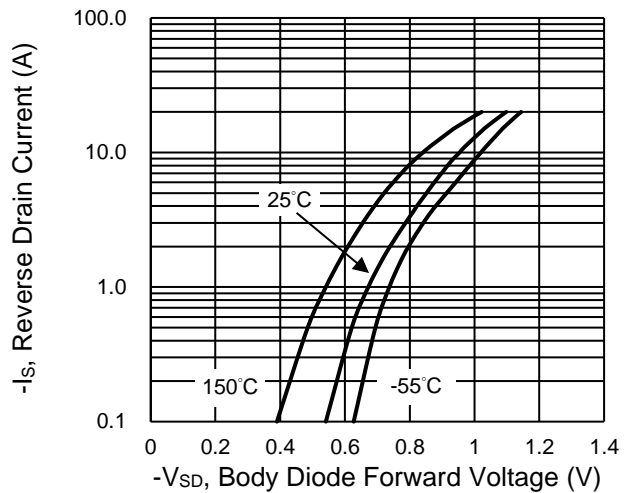
BV_{DSS} vs. Junction Temperature



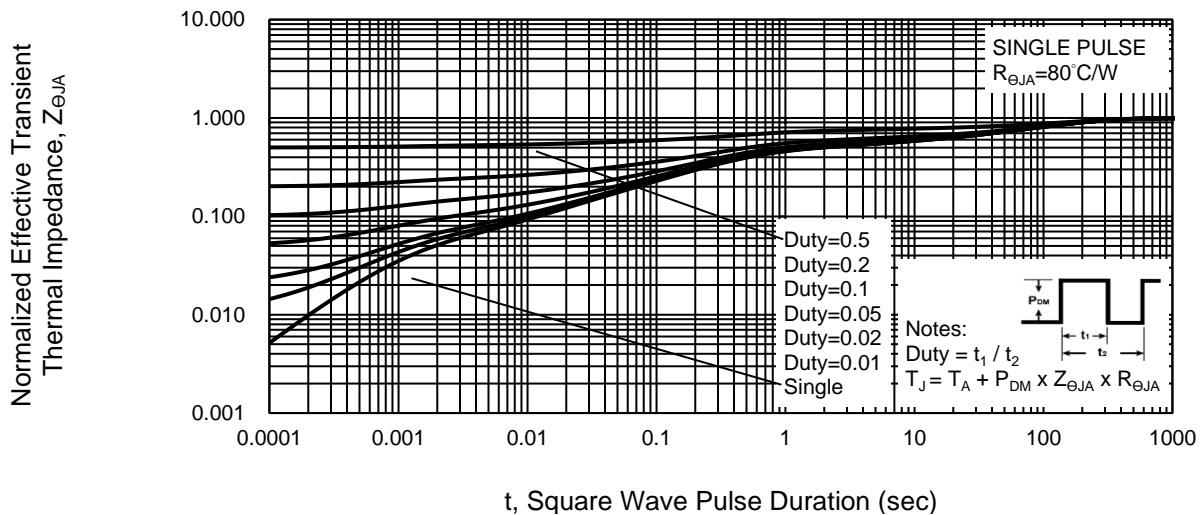
Maximum Safe Operating Area, Junction-to-Ambient



Source-Drain Diode Forward Current vs. Voltage



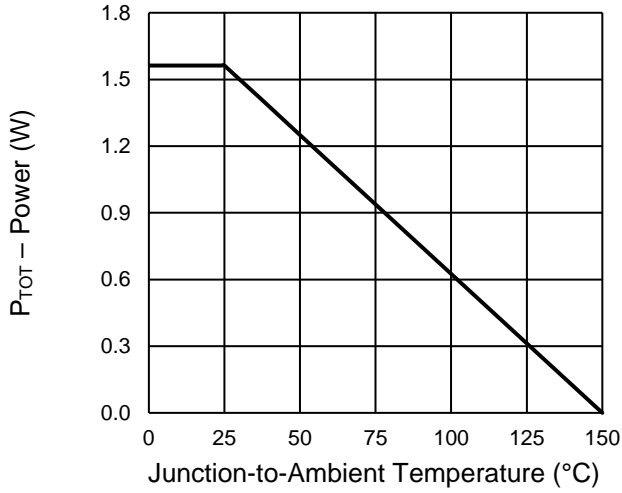
Normalized Thermal Transient Impedance, Junction-to-Ambient



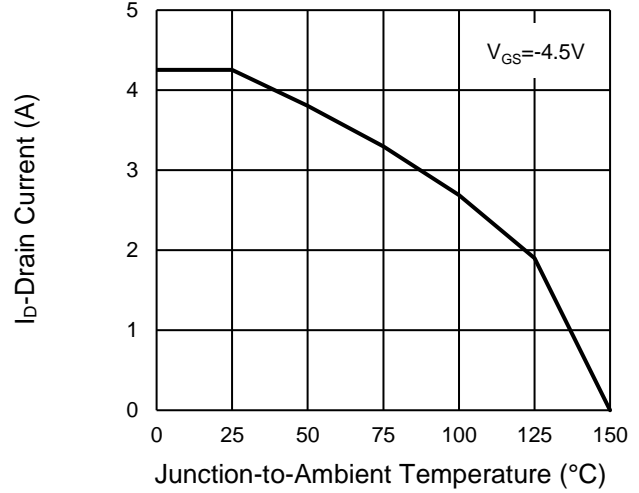
CHARACTERISTICS CURVES

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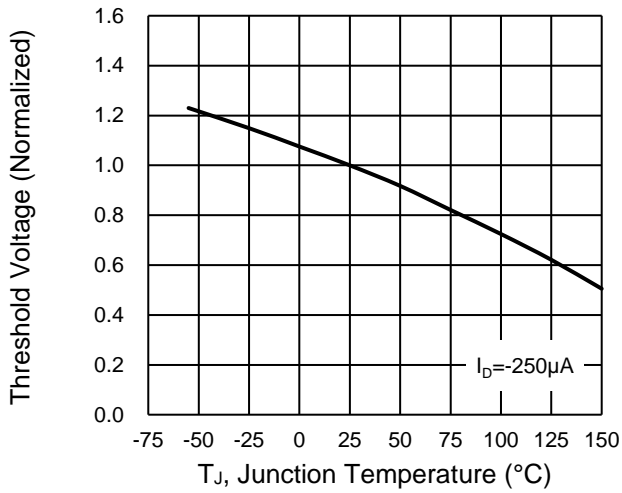
Power Dissipation



Drain Current

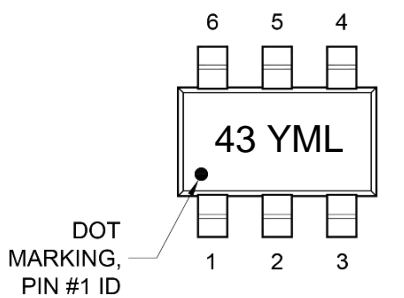
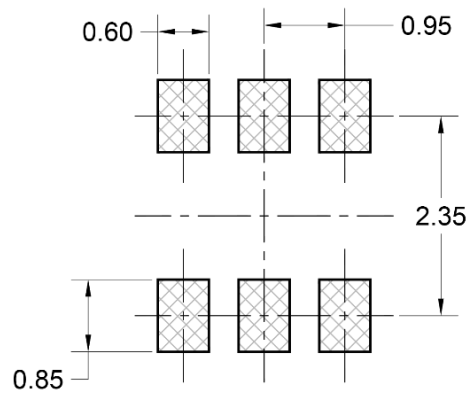
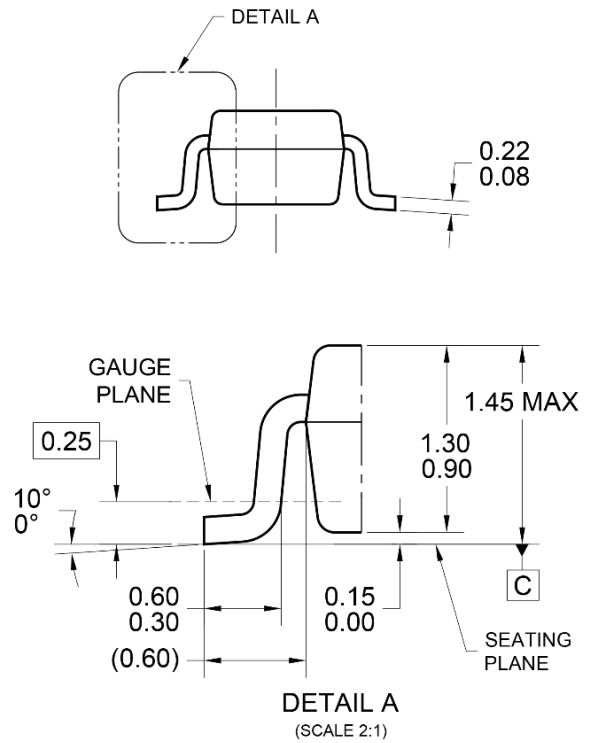
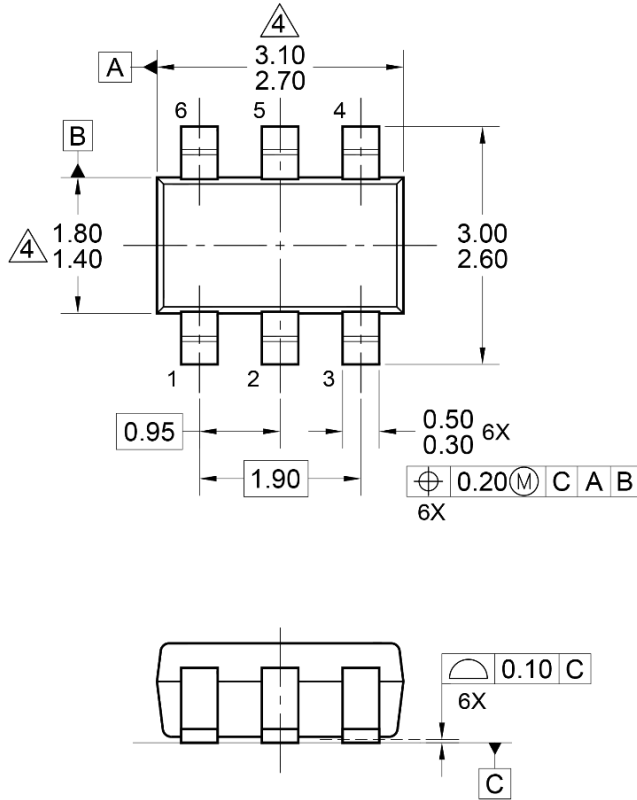


Normalized gate threshold voltage vs Temperature



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SOT-26



MARKING DIAGRAM

- 43 = Device marking
- Y = Year Code
- M = Month Code for Halogen Free Product
(O=Jan, P=Feb, Q=Mar, R=Apr, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)
- L = Lot Code

NOTES: UNLESS OTHERWISE SPECIFIED

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. PACKAGE OUTLINE REFERENCE: JEDEC MO-178, VARIATION AB.
4. MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DWG NO. REF: HQ2SD07-SOT26-027 REV A.

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